



### 700V N-Channel MOSFET

Voltage

700 V

**Current** 

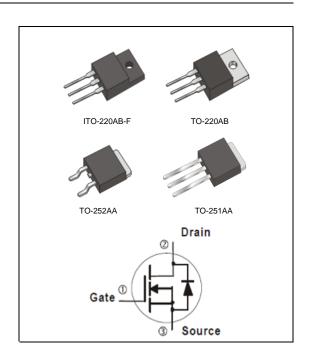
6 A

#### **Features**

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V,I<sub>D</sub>@3A<1.7Ω
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

### **Mechanical Data**

- Case: TO-251AA,TO-252AA,TO-220AB, ITO-220AB-F Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AA Approx. Weight: 0.0104 ounces, 0.297grams
- TO-252AA Approx. Weight: 0.0104 ounces, 0.297grams
- TO-220AB Approx. Weight: 0.067 ounces, 1.89 grams
- ITO-220AB-F Approx. Weight: 0.068 ounces, 2 grams



# **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

| PARAMETER                              |                      | SYMBOL          | TO-251AA    | TO-220AB | ITO-220AB-F | TO-252AA | UNITS |
|--|----------------------|-----------------|-------------|----------|-------------|----------|-------|
| Drain-Source Voltage                   |                      | V <sub>DS</sub> | 700         |          |             |          | ٧     |
| Gate-Source Voltage                    |                      | $V_{GS}$        | <u>+</u> 30 |          |             |          | ٧     |
| Continuous Drain Current               |                      | I <sub>D</sub>  | 6           |          |             |          | Α     |
| Pulsed Drain Current                   |                      | I <sub>DM</sub> | 24          |          |             |          | Α     |
| Single Pulse Avalanche Energy (Note 1) |                      | E <sub>AS</sub> | 321         |          |             |          | mJ    |
| Power Dissipation                      | T <sub>C</sub> =25°C | P <sub>D</sub>  | 128         | 142      | 45          | 128      | W     |
|  | Derate above 25°C    |                 | 1.02        | 1.14     | 0.36        | 1.02     | W/°C  |
| Operating Junction and                 |                      | $T_J, T_{STG}$  | 55, 450     |          |             |          |       |
| Storage Temperature Range              |                      |                 | -55~150     |          |             |          | °C    |
| Typical Thermal resistance             |                      |                 |             |          |             |          |       |
| - Junction to Case                     |                      | $R_{	heta JC}$  | 0.98        | 0.88     | 2.78        | 0.98     | °C/W  |
| - Junction to Ambient                  |                      | $R_{\theta JA}$ | 110         | 62.5     | 120         | 110      |       |

• Limited only By Maximum Junction Temperature





# Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| PARAMETER                        | SYMBOL              | TEST CONDITION   | MIN. | TYP.        | MAX.         | UNITS |
|----------------------------------|---------------------|--|------|-------------|--------------|-------|
| Static                           |                     |  |      |             |              |       |
| Drain-Source Breakdown Voltage   | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V,I <sub>D</sub> =250uA                  | 700  | -           | -            | V     |
| Gate Threshold Voltage           | $V_{GS(th)}$        | $V_{DS}=V_{GS}$ , $I_{D}=250uA$                            | 2    | 2.8         | 4            | V     |
| Drain-Source On-State Resistance | R <sub>DS(on)</sub> | $V_{GS}=10V,I_{D}=3A$                                      | -    | 1.47        | 1.7          | Ω     |
| Zero Gate Voltage Drain Current  | I <sub>DSS</sub>    | V <sub>DS</sub> =700V,V <sub>GS</sub> =0V                  | -    | 0.03        | 1.0          | uA    |
| Gate-Source Leakage Current      | I <sub>GSS</sub>    | $V_{GS}=\underline{+}30V, V_{DS}=0V$                       | -    | <u>+</u> 10 | <u>+</u> 100 | nA    |
| Diode Forward Voltage            | $V_{SD}$            | I <sub>S</sub> =6A,V <sub>GS</sub> =0V                     | -    | 0.87        | 1.4          | V     |
| Dynamic (Note 4)                 |                     |  |      |             |              |       |
| Total Gate Charge                | $Q_g$               |  | -    | 16.5        | -            | nC    |
| Gate-Source Charge               | $Q_gs$              | $V_{DS}$ =560V, $I_{D}$ =6A, $V_{GS}$ =10V (Note 2,3)      | -    | 4.8         | -            |       |
| Gate-Drain Charge                | $Q_{gd}$            | V <sub>GS</sub> =10V \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ | -    | 5.7         | -            |       |
| Input Capacitance                | Ciss                | ), OEN N ON  | -    | 831         | -            | pF    |
| Output Capacitance               | Coss                | V <sub>DS</sub> =25V, V <sub>GS</sub> =0V,                 | -    | 92          | -            |       |
| Reverse Transfer Capacitance     | Crss                | f=1.0MHZ   | -    | 0.8         | -            |       |
| Turn-On Delay Time               | td <sub>(on)</sub>  |  | -    | 25          | -            | ns    |
| Turn-On Rise Time                | t <sub>r</sub>      | $V_{DD}$ =350V, $I_{D}$ =6A,                               | -    | 38          | -            |       |
| Turn-Off Delay Time              | td <sub>(off)</sub> | $R_G=25\Omega$ (Note 2,3)                                  | -    | 49          | -            |       |
| Turn-Off Fall Time               | t <sub>f</sub>      |  | -    | 30          | -            |       |
| Drain-Source Diode               |                     |  |      |             |              |       |
| Maximum Continuous Drain-Source  |                     |  | -    | -           | 6            | А     |
| Diode Forward Current            | l <sub>S</sub>      |  |      |             |              |       |
| Maximum Pulsed Drain-Source      |                     |  |      |             | 24           | ^     |
| Diode Forward Current            | I <sub>SM</sub>     |  | -    | -           | 24           | А     |
| Reverse Recovery Time            | trr                 | V <sub>GS</sub> =0V, I <sub>S</sub> =6A                    | -    | 531         | -            | ns    |
| Reverse Recovery Charge          | Qrr                 | dI <sub>F</sub> / dt=100A/us (Note 2)                      | -    | 3.3         | -            | uC    |

#### NOTES:

- 1. L=30mH,  $I_{AS}$ =4.5A,  $V_{DD}$ =50V,  $R_{G}$ =25ohm, Starting  $T_{J}$ =25 $^{\circ}$ C
- 2. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 3. Essentially independent of operating temperature typical characteristics.
- 4. Guaranteed by design, not subject to production testing





#### **TYPICAL CHARACTERISTIC CURVES**

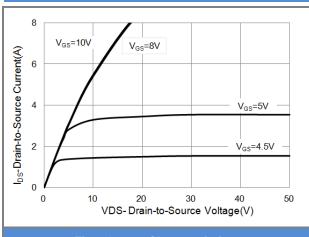
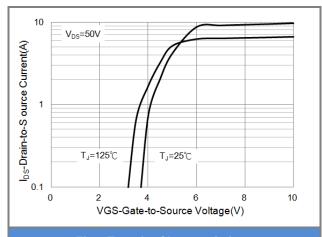


Fig.1 Output Characteristics



**Fig.2 Transfer Characteristics** 

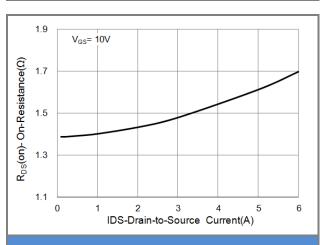


Fig.3 On-Resistance vs. Drain Current

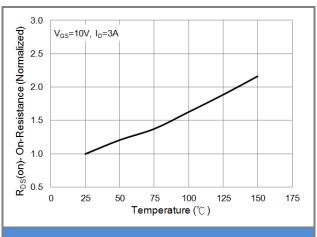
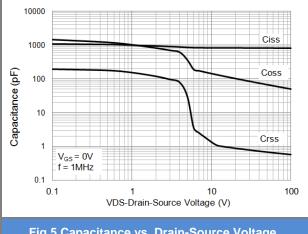


Fig.4 On-Resistance vs. Junction Temperature





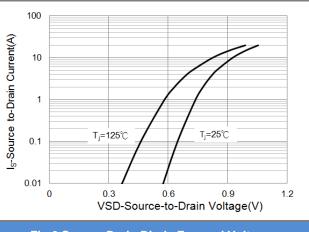


Fig.6 Source-Drain Diode Forward Voltage





#### **TYPICAL CHARACTERISTIC CURVES**

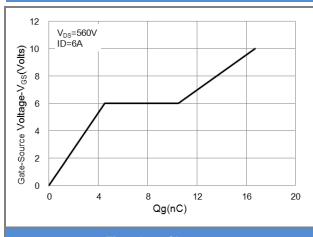


Fig.7 Gate Charge

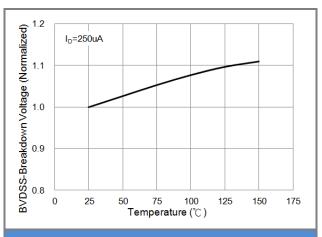


Fig.8 BV<sub>DSS</sub> vs. Junction Temperature

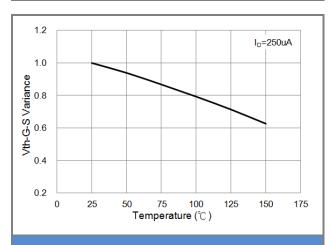


Fig.9 Threshold Voltage Variation with Temperature

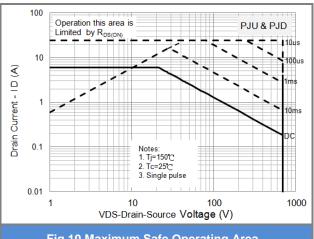
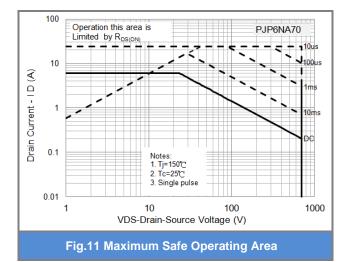
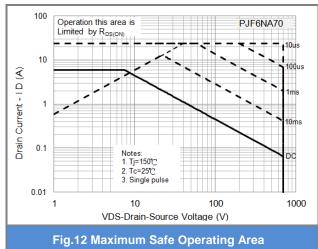


Fig.10 Maximum Safe Operating Area









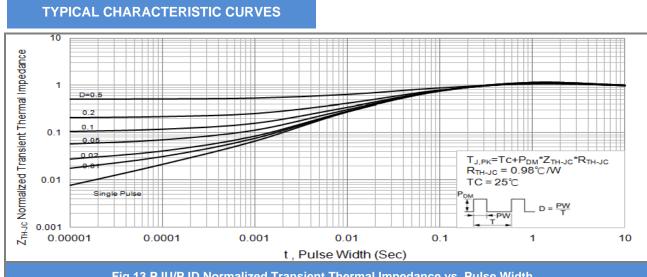


Fig.13 PJU/PJD Normalized Transient Thermal Impedance vs. Pulse Width

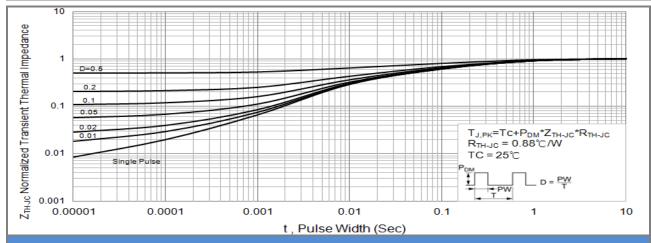


Fig.14 PJP6NA70 Normalized Transient Thermal Impedance vs. Pulse Width

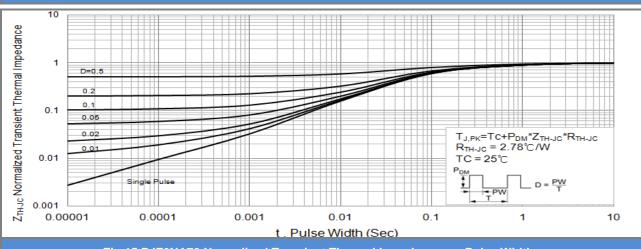
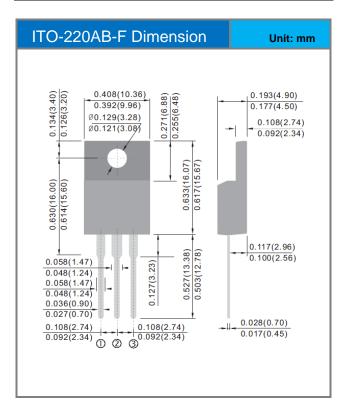


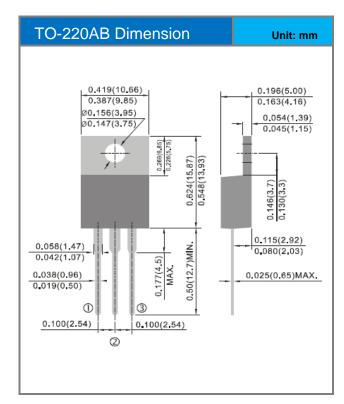
Fig.15 PJF6NA70 Normalized Transient Thermal Impedance vs. Pulse Width

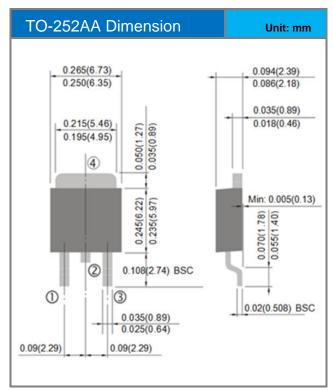


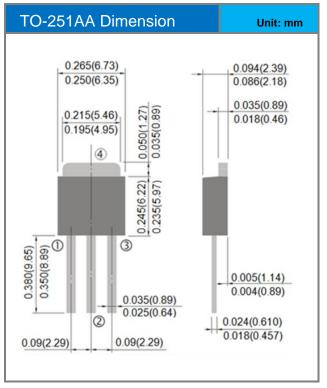


### **Packaging Information**













### PART NO PACKING CODE VERSION

| Part No Packing Code | Package Type | Packing type        | Marking | Version      |  |
|----------------------|--------------|---------------------|---------|--------------|--|
| PJU6NA70_T0_00001    | TO-251AA     | 80pcs / Tube        | U6NA70  | Halogen free |  |
| PJD6NA70_L2_00001    | TO-252AA     | 3,000pcs / 13" reel | D6NA70  | Halogen free |  |
| PJP6NA70_T0_00001    | TO-220AB     | 50pcs / Tube        | P6NA70  | Halogen free |  |
| PJF6NA70_T0_00001    | ITO-220AB-F  | 50pcs / Tube        | F6NA70  | Halogen free |  |





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